



Quantum Hall states and fractional topological insulator states in strained graphene

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Fractional topological phases and broken time reversal symmetry in strained graphene, P. Ghaemi, J.C., D.N. Sheng, and A. Vishwanath, Phys. Rev. Lett. 108, 266801 (2012)



Ashvin Vishwanath (Berkeley)







Quick history of Topological phases of electrons in crystals

Integer and Fractional Quantum Hall effect(1981,1983)2D electrons in strong magnetic field: Si, GaAs, graphene,...

Topological insulators with strong spin-orbit coupling2D: graphene, HgTe quantum wells(2005,2007)3D: BiSb, Bi2Se3, Bi2Te3, HgTe under strain(2006,2008)

Zoology of Chern insulators with **no overall/net magnetic field 2D:** Haldane 1988 Various models of **Fractional Chern insulators (2011)**

Rough/partial classification of topological phases in the absence of a global uniform field

Time-reversal Symmetry	Free electrons	Interacting electrons
NO	Chern insulator No Landau levels Dispersive Bloch bands with nonzero Chern number	Fractional Chern insulators Flattened Bloch band
YES	Topological insulator Experimental evidences: HgTe, Bi2Se3, Bi2Te3	Fractional topological insulators

Our motivation was to propose **graphene under strain as**:

1) A possible experimental platform to realize **topological phases** in the **absence of external magnetic field**

2) A system with a competition between Time-reversal symmetric phases and Time-reversal breaking phases

3) A possible (valley) Fractional Topological Insulator under some fine-tuning of the interactions

Outline

Pseudomagnetic fields in strained/deformed graphene Large valley-dependent fields Time-reversal (TR) **invariance** (*real magnetic field* = 0)

Experimental signatures (short review)

Observation of large pseudo-fields: **60T**, **100T**, **300T**,... ! **Pseudo Landau level structure (PLL)**

Interaction driven phases (our theoretical work) Effet of the **Coulomb interaction** in a **partially filled PLL** Fractional quantum Hall states (**breaks** TR) Fractional topological insulators (TR **invariant** state)

Graphene (unstrained and B=0)

Two sublattices A and B

Honeycomb lattice

Band structure (pi orbitals)



2 Dirac points at K and K'

Microscopic Tight binding model:

$$H_0 = \sum_{\mathbf{r}_{mn}} \sum_{a=1,2,3} t \, a^{\dagger}(\mathbf{r}_{mn}) b(\mathbf{r}_{mn} + \boldsymbol{\delta}_a) + h.c.$$

Low energy theory: Dirac Hamiltonian



Smooth deformation of the bonds



Low energy theory: Dirac Hamiltonian

$$\frac{H_{\xi}}{H_{\xi}} = v_F(\xi \Pi_x^{\xi} \sigma_x + \Pi_y^{\xi} \sigma_y)$$

$$\mathbf{\Pi}^{\xi} = \mathbf{p} + \boldsymbol{\xi} \delta \mathbf{p}$$

Dirac point motion





Momentum shift = Potential vector

$$\Pi^{\xi} = \mathbf{p} + \underbrace{\xi \delta \mathbf{p}}_{\xi e \mathbf{A}}$$

Induced vector potentials are opposite in the valleys



Uniform deformation



Dirac points shifted but NO pseudomagnetic field (curl A=0)

M. O. Goerbig, J.-N. Fuchs, G. Montambaux, and F. Piéchon, PRB **78**, 045415 (2008) G. Montambaux, F. Piéchon, J.-N. Fuchs, and M. O. Goerbig, PRB **80**, 153412 (2009) Pics from M.O. Goerbig, RMP **23**, 1193 (2011)

Non uniform deformation yields finite fields

Arbitrary deformation leads in general to: Non uniform field and complicated band structure...

Class of deformations yielding to Uniform magnetic field in a given valley Dirac cones are expected to split into flat Landau levels

F. Guinea, M.I. Katsnelson, and A.K. Geim, Nature Physics, 2009



F. Guinea, M.I. Katsnelson, and A.K. Geim, Nature Physics, 2009

Relation valley-sublattice (n=0 Landau level)

Real magnetic field: K on B sublattice and K' on A sublattice.



Pseudo field: Both K and K' on the same sublattice (B).



Two natural questions:

1- Experimental evidences of those large fields and associated Landau levels ?

2- Can we have Fractional Quantum Hall states in the partially filled Landau levels induced by pure strain ?

PART II: Experiments on deformed graphene systems

Crommie (Berkeley): real graphene (Science 2011)

Lin He (Beijing University): real bilayer graphene (ArXiv 2012)

Manoharan (Stanford): molecular graphene (Nature 2012)

Esslinger (ETH Zurich): fermionic cold atoms (Nature 2012)

Strained graphene (Crommie, Berkeley)

Real graphene on top of a Pt substrate

Nanoscale bubbles scanned by STM







 $\frac{sgn(n)\sqrt{|n|}}{\text{Typical fields: 300 Tesla !}}$





Twisted graphene bilayer (Lin He, Beijing)



Non relativistic Landau levels

Why strained induced fields are so large in graphene?

$$B_{eff} \simeq \frac{\Phi_0}{a^2} \cdot \frac{\delta a}{\delta y}$$

10⁵ Tesla 10⁻³

But with a limitation on the strained region **size**

 L_y



Molecular graphene (Manoharan, Stanford)





100-1000 molecules deposited one by one on Cu surface

Lattice spacing a=2 nm 10 times larger than atomic graphene 10 times smaller than patterned 2DEG

2 nm



DOS by STM

Triaxial deformation

Typical pseudofields: 60 Tesla ! in «pseudographene»

Density of free electrons fixed

Lattice constant of the CO molecules grid can be varied

Highly controlled system

Fermionic cold atoms (Esslinger, ETH Zurich)







PART III: Interactions in a partially filled pseudo Landau level

Interaction Hamiltonian

Integer filling of spin-valley subbands

Fractional filling of the spin-valley degenerated PLL

Interaction Hamiltonian

Long range Coulomb interaction: $V(\mathbf{r}_i - \mathbf{r}_j) = e^2/4\pi\epsilon|\mathbf{r}_i - \mathbf{r}_j|$

$$H_{int} = \sum_{\mathbf{r}_{i} \neq \mathbf{r}_{j}} V(\mathbf{r}_{i} - \mathbf{r}_{j}) n(\mathbf{r}_{i}) n(\mathbf{r}_{j}) + U_{0} \sum_{\mathbf{r}_{i}} n(\mathbf{r}_{i}) n(\mathbf{r}_{i}) + U_{nnn} \sum_{\langle \mathbf{r}_{i}, \mathbf{r}_{j} \rangle} n(\mathbf{r}_{i}) n(\mathbf{r}_{j})$$

$$e^{2/4\pi\epsilon a_{0}} \int_{0}^{4} \int_{0}^{4}$$

Half-filled n=0 Pseudo Landau Level

Valley ferromagnet:
$$\Psi_V = \prod_k c^{\dagger}_{R,k,\uparrow} c^{\dagger}_{R,k,\downarrow} |0\rangle$$

Spin ferromagnet: $\Psi_S = \prod_k c^{\dagger}_{R,k,\uparrow} c^{\dagger}_{L,k,\uparrow} |0\rangle$

Reminiscent of the same problem for a real field:

J. Alicea and M.P.A. Fisher, Phys. Rev. B 74, 075422, 2006

M. O. Goerbig, R. Moessner, and B. Douçot, Phys. Rev. B 74, 161407, 2006

but here SU(4) symmetry is reduced to SU(2)xZ2

Coulomb only

Dominant density-density terms: Spin ferromagnet and Valley Ising ferromagnet have the same Hartree-Fock energy

Backscattering terms favor the Ising valley ferromagnet



Some density-density terms

Backscattering term

Coulomb + on-site Hubbard corrections U0



T.O. Wehling et al. PRL 106, 236805 (2011)

On-site repulsion favors the spin ferromagnet

No Zeeman effect at all (in contrast to real field)

Numerical Hartree-Fock calculation of the groundstate energies (Donna Sheng)



Shows the sensitivity to local part of the interaction

Fractional filling 2/3 graphene

Two scenarios:

1) Electrons **valley polarize** and realize a **FQH state in the large effective field of this valley. Time-reversal** symmetry is **spontaneously broken**.

2) Electrons populate the two valleys. Time-reversal invariant state.

Graphene at fractional filling 2/3 (of the n=0 PLL)

Exact diagonalization (Donna Sheng)

$$N_e = 8$$

 $N_{\phi} = 12$
 $\Phi_0/48$ per hexagon on a 24*24 lattice

1) Groundstate and excited states **energies**

2) Wavefunctions

3) Chern number

Grounstate energy for Spinless electrons

Valley polarized 2/3 state

Valley symmetric (1/3+1/3) state

Valley K: +B Valley K': -B

Grounstate energy for Spinless electrons



Valley polarized state is the most stable for pure Coulomb (U=0 points)

Properties of the valley polarized state

3-fold degenerate groundstate on the torus

Total Chern number 2 for the 3-degenerated states (calculated by a mesh method in phase twist space)

This state is qualitatively similar to a FQH state at 2/3 It is also a spin singlet state (for spinful electrons). but realized in very large effective fields (up to hundreds of Tesla)

How to destabilize this state ?

Grounstate energy for Spinless electrons



Valley symmetric state can be obtained by decreasing the next-nearest-neighbor interaction Unnn^op (between opposite valleys)

Low energy spectrum for spinless electrons



9 fold quasi-degenerate groundstate

Valley fractional topological insulator (FTI)

Properties of this state

Boundary-phase twist



9-fold degenerated valley Fractional Topological Insulator

Phase diagram: spinless case



Phase diagram: spinless case



Spin FTI from Hua Chen and Kun Yang, PRB 85, 195113 (2012)

Grounstate energy for Spinful electrons

Valley polarized + spin singlet for Unnn=0 (Pure Coulomb)

Valley unpolarized + spin singlet stabilized by Unnn<0 but no fractional topological insulator :-(

Experiments vs theory

Status of experiments:

- Spectroscopy of pseudo Landau levels
- Few flux quanta in samples
- No magnetotransport experiments so far

Possible improvements:

- Samples on insulating substrate
- Bigger samples (larger orbital degeneracy of the PLL)

Interactions in current experiments:

- Strained graphene and molecular graphene: interactions are screened by metallic substrate

Real graphene: **valley polarized state** at partial filling. Spin (or valley) Hall ferromagnet at neutrality.

Tuned interactions: valley Fractional Topological Insulator

New platforms to generate high fields and correlated phases.

Potentially the richness of Quantum Hall physics but with additional competition between time-reversal breaking (FQH like) and time reversal invariant states.

Still a lot to study: activation gaps, excitations, role of additional real magnetic field, superconductivity ...

Thanks for your attention !

Chern insulators (also Quantum Anomalous Hall phases)

Lattice model + local fluxes (complex hopping matrix elements)

Local fluxes break Time-Reversal symmetry and allow for **Quantum Hall Effect** for Bloch states (no Landau levels)

Illustrations from Wu, Regnault, Bernevig, PRB 2012 and Lauchli et al. ArXiv 2012

Valley FTI: decoupled $1/3 + 1/3^*$

Properties of this valley FTI

Adiabatic continuity with the decoupled valley state

Motivations for FTIs (no overall magnetic field)

Lattice system with Quantum Hall effect but no Landau levels

Are the states in FCIs similar to FQH states in some limit ?

Same serie of fractions or not ? Dependence on the underlying lattice model ?

FTI in a band with high Chern number N>1

etc...

$$C = \frac{i}{4\pi} \int \int d\theta_x d\theta_y \left[\left\langle \frac{\partial \Psi}{\partial \theta_x} | \frac{\partial \Psi}{\partial \theta_y} \right\rangle - \left\langle \frac{\partial \Psi}{\partial \theta_y} | \frac{\partial \Psi}{\partial \theta_x} \right\rangle \right]$$

$$C^{\alpha,\beta} = \frac{i}{4\pi} \iint d\theta_x^{\alpha} d\theta_y^{\beta} \left[\left\langle \frac{\partial \Psi}{\partial \theta_x^{\alpha}} \middle| \frac{\partial \Psi}{\partial \theta_y^{\beta}} \right\rangle - \left\langle \frac{\partial \Psi}{\partial \theta_y^{\beta}} \middle| \frac{\partial \Psi}{\partial \theta_x^{\alpha}} \right\rangle \right]$$

Tuned graphene: spinful case

Spin polarized superconductor